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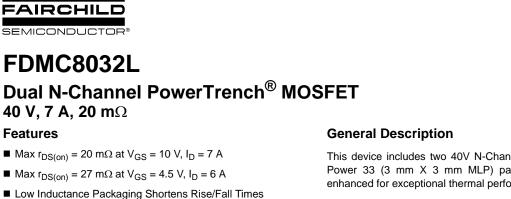


ON Semiconductor®

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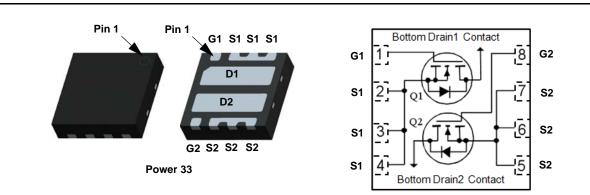


- Lower Switching Losses
- 100% Rg Tested
- Termination is Lead-free and RoHS Compliant

This device includes two 40V N-Channel MOSFETs in a dual Power 33 (3 mm X 3 mm MLP) package. The package is enhanced for exceptional thermal performance.

Applications

- Battery Protection
- Load Switching
- Point of Load



MOSFET Maximum Ratings TA = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			40	V	
V _{GS}	Gate to Source Voltage			±20	V	
	Drain Current -Continuous	T _C = 25 °C		20		
I _D	-Continuous	T _A = 25 °C	(Note 1a)	7	A	
	-Pulsed		(Note 4)	50		
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	13	mJ	
P _D	Power Dissipation	T _C = 25 °C		12	w	
	Power Dissipation	T _A = 25 °C	(Note 1a)	1.9	vv	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	9.7	°C 44/
R_{\thetaJA}	Thermal Resistance, Junction to Ambient (Note 1a)	65	°C/W

Package Marking and Ordering Information

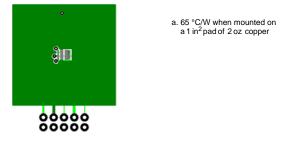
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC8032L	FDMC8032L	Power 33	13 "	12 mm	3000 units

October 2013

FDMC8032L
Dual
N-Channel
PowerTrench [®]
MOSFET

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	cteristics						
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	40			V	
ΔBV_{DSS} ΔT_J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		23		mV/°C	
IDSS	Zero Gate Voltage Drain Current	V _{DS} = 32 V, V _{GS} = 0 V			1	μA	
I _{GSS}	Gate to Source Leakage Current, Forward	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA	
On Chara	cteristics			·		·	
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250 μA	1.0	1.8	3.0	V	
$\Delta V_{GS(th)}$ ΔT_J	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-5		mV/°C	
0		V _{GS} = 10 V, I _D = 7 A		16	20		
r	Static Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, I_D = 6 \text{ A}$		21	27	mΩ	
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 7 A T _J = 125 °C		23	29	- 1122	
9 _{FS}	Forward Transconductance	$V_{DD} = 5 V, I_D = 7 A$		27		S	
C _{iss}	Characteristics Input Capacitance Output Capacitance	V _{DS} = 20 V, V _{GS} = 0 V f = 1MHz		513 137	720	pF	
C _{oss}	Output Capacitance			137	195	pF	
C _{rss}	Reverse Transfer Capacitance			9.3	15	pF	
R _g	Gate Resistance		0.1	2.6	3.6	Ω	
Switching	g Characteristics						
t _{d(on)}	Turn-On Delay Time			5.5	11	ns	
t _r	Rise Time	V _{DD} = 20 V, I _D = 7 A		1.2	10	ns	
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 V, R_{GEN} = 6 \Omega$		13	24	ns	
t _f	Fall Time			1.3	10	ns	
0	Total Gate Charge	V _{GS} = 0 V to 10 V		7.6	11	nC	
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 V \text{ to } 4.5 V V_{DD} = 20 V$		3.6	5.1	nC	
Q _{gs}	Gate to Source Charge	I _D = 7 A		1.5		nC	
Q _{gd}	Gate to Drain "Miller" Charge			1.0		nC	
Drain-Soι	arce Diode Characteristics						
		$V_{GS} = 0 V, I_S = 7 A$ (Note 2)		0.85	1.3		
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 1.4 A$ (Note 2)		0.75	1.2	- V	
t _{rr}	Reverse Recovery Time			16	29	ns	
Q _{rr}	Reverse Recovery Charge	- I _F = 7 A, di/dt = 100 A/μs		3.9	10	nC	

1. R_{0JA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0JC} is guaranteed by design while R_{0CA} is determined by the user's board design.



2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0 %.

3. EAS of 13 mJ is based on starting T_J = 25 °C, L = 3 mH, I_{AS} = 3 A, V_{DD} = 40 V, V_{GS} = 10 V. 100% tested at L = 0.1 mH, I_{AS} = 11 A. 4. Pulse Id refers to Figure.11 Forward Bias Safe Operation Area.

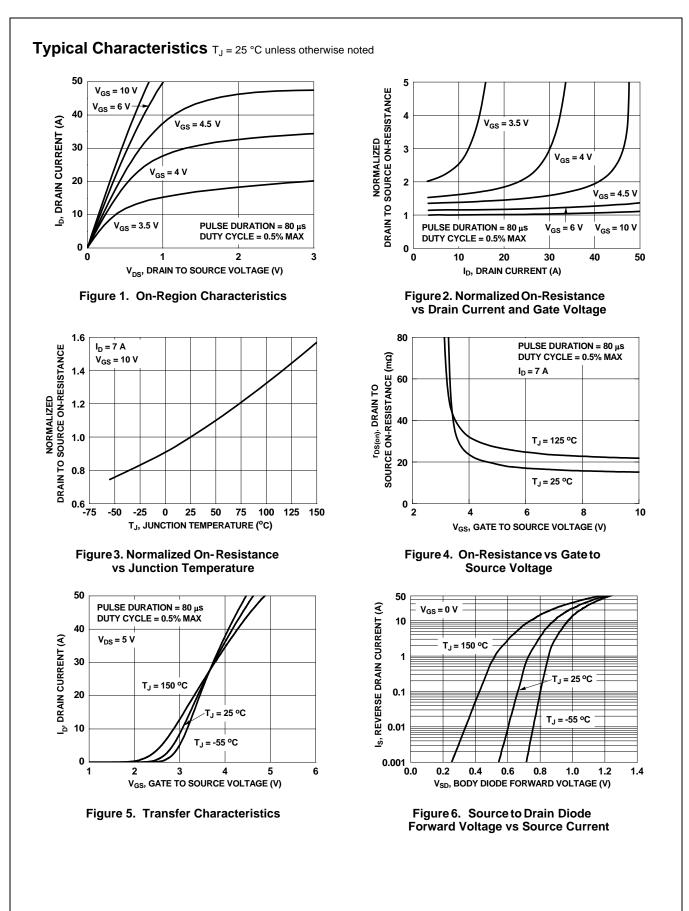
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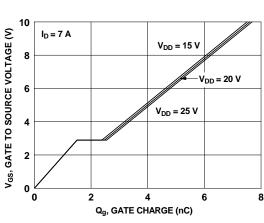
b. 155 °C/W when mounted on

a minimum pad of 2 oz copper



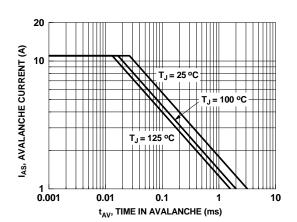
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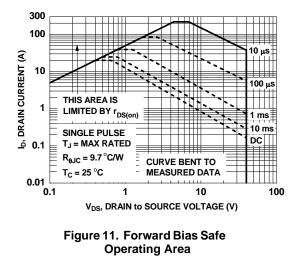


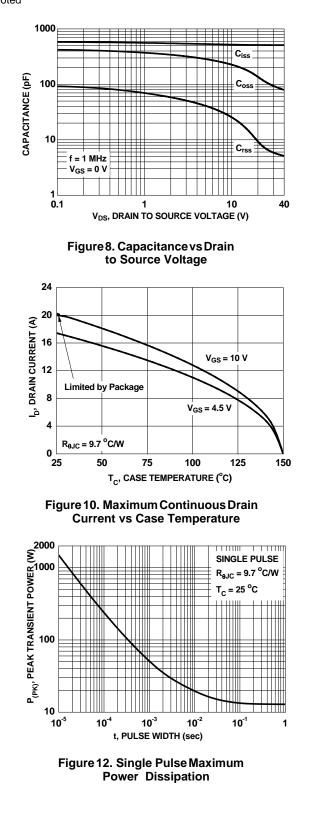
Typical Characteristics T_J = 25 °C unless otherwise noted

Figure 7. Gate Charge Characteristics

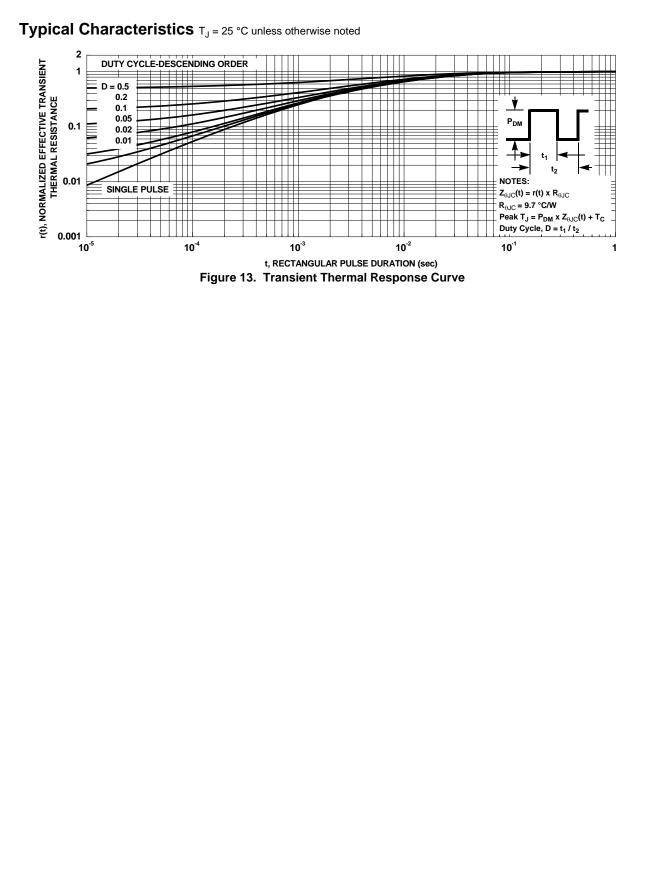


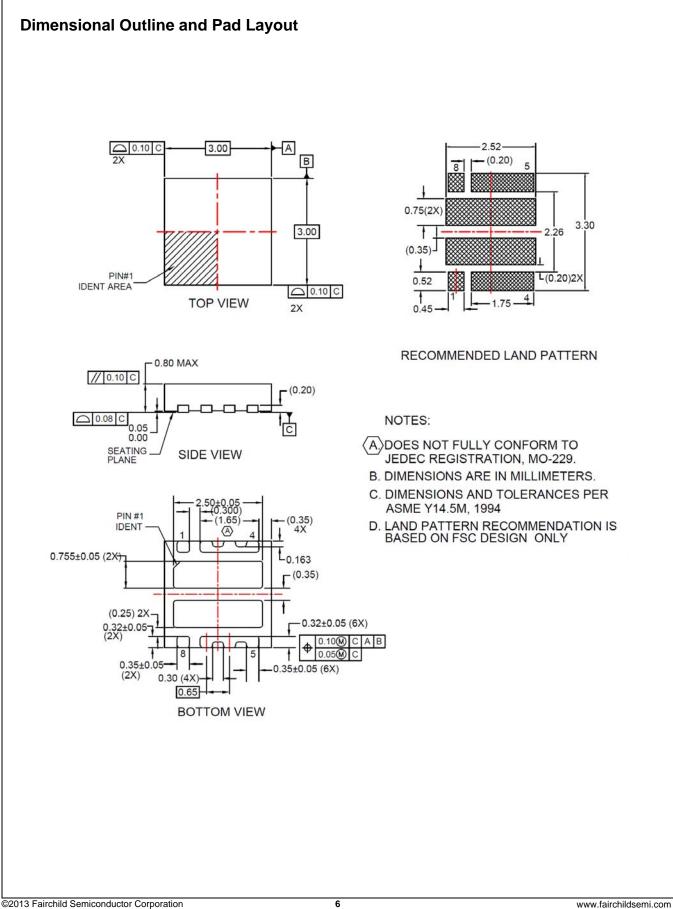






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DMC8032L Dual N-Channel PowerTrench[®] MOSFET

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